



#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BVDSS	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
001/	$38m\Omega$ @ $V_{GS} = 4.5V$	4.8A
20V	$45m\Omega$ @ $V_{GS} = 2.5V$	4.5A

## **Description**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- General purpose interfacing switches
- Power management functions

### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMN2055UQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

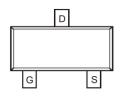
#### **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)

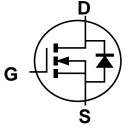








Top View



Equivalent Circuit

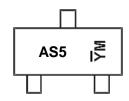
### Ordering Information (Note 4)

Part Number	Backago	Paci	king
Part Number	Package	Qty.	Carrier
DMN2055UQ-7	SOT23	3,000	Tape & Reel
DMN2055UQ-13	SOT23	10,000	Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\frac{\text{AS5} = \text{Product Type Marking Code}}{\text{YM} = \text{Date Code Marking}}$  $\frac{\text{Y} = \text{Last Digit of Year (ex: J = 2022)}}{\text{M} = \text{Month (ex: 4 = April)}}$ 

#### Date Code Key

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code		J	K	L	М	N	0	Р	R	S	T	U
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characte	eristic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage		Vgss	±8	V	
Continuous Drain Current (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +85°C	lo	4.8 3.8	Α	
Pulsed Drain Current (10µs Pulse, Du	ty Cycle = 1%)		I <sub>DM</sub>	25	А

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	162	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	1.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	113	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

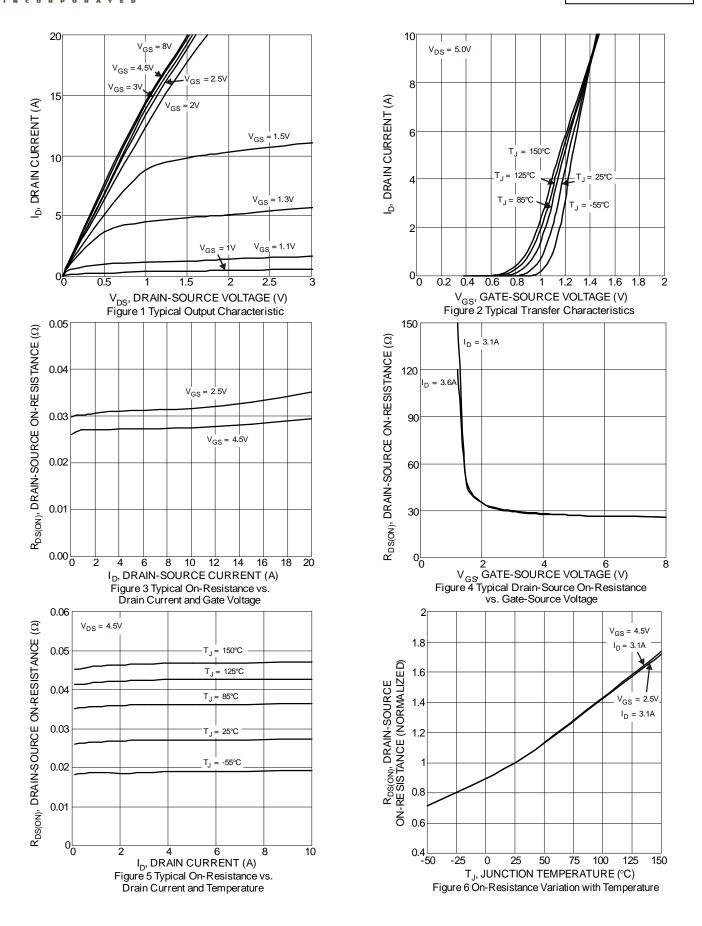
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$		
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	_	_	1.0	μΑ	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V		
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.4	_	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$		
Static Drain-Source On-Resistance	-		28	38	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$		
Static Drain-Source On-Resistance	RDS(ON)	_	32	45	11177	Vgs = 2.5V, ID = 3.1A		
Diode Forward Voltage	VsD	_	0.7	1.0	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 1A		
DYNAMIC CHARACTERISTICS (Note 8)	•	•		•	•			
Input Capacitance	Ciss	_	400	_	pF			
Output Capacitance	Coss	_	55	_	pF	$V_{DS} = 10V, V_{GS} = 0V,$ - f = 1.0MHz		
Reverse Transfer Capacitance	Crss	_	37	_	pF	T = 1.0WHZ		
Gate Resistance	Rg	_	3.7	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$		
Total Gate Charge	Qg	_	4.3	_	nC			
Gate-Source Charge	Qgs	_	0.3	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$		
Gate-Drain Charge	$Q_{GD}$	_	4.8	_	nC	-I <sub>D</sub> = 6A		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.8	_	ns			
Turn-On Rise Time	t <sub>R</sub>		2.7	_	ns	V <sub>DD</sub> = 10V, V <sub>GS</sub> = 5V,		
Turn-Off Delay Time	tD(OFF)		15.4	_	ns	$R_L = 1.7\Omega$ , $R_G = 6\Omega$		
Turn-Off Fall Time	t <sub>F</sub>	_	4.4	_	ns	1		
Reverse Recovery Time	t <sub>RR</sub>	_	6.8	_	ns	$I_F = 1.0A$ , $di/dt = 100A/\mu s$		
Reverse Recovery Charge	Qrr	_	1.2	_	nC	IF = 1.0A, di/dt = 100A/µs		

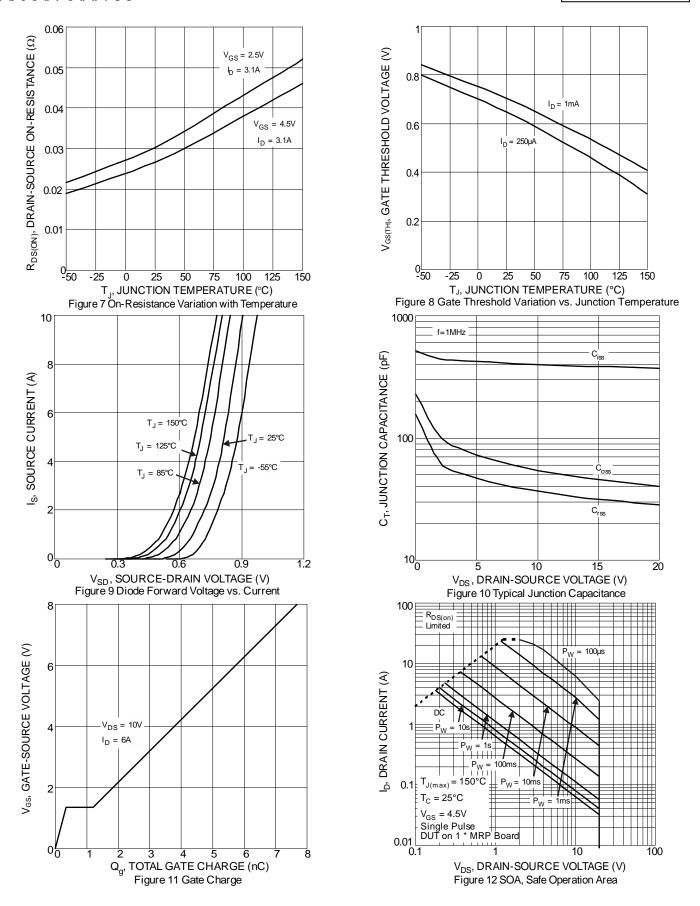
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

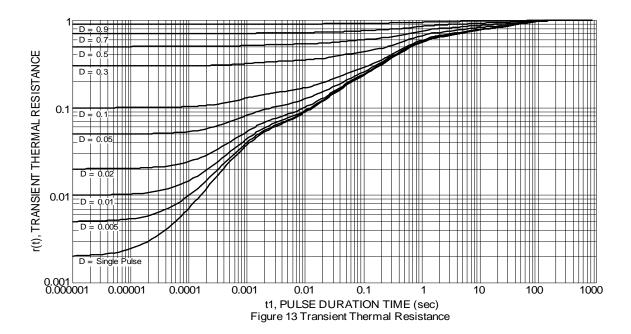










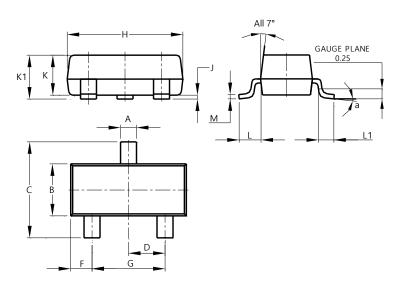




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

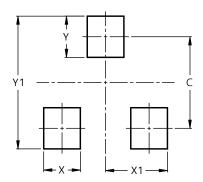


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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